



60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

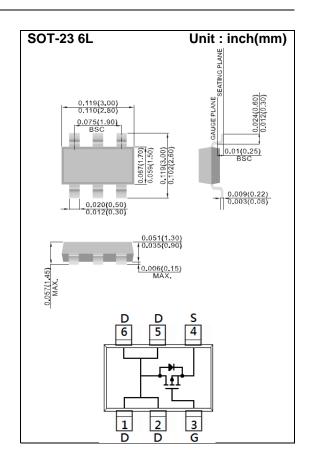
-3.2A

Features

- R_{DS(ON)}, V_{GS}@-10V,I_D@-3.2A<110mΩ
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-1.6A<130m\Omega$
- High switching speed.
- Improved dv/dt capability.
- Low Gate Charge.
- Low reverse transfer capacitance.
- Lead free in compliance with EU RoHS 2.0.
- Green molding compound as per IEC 61249 Std.

Mechanical Data

- Case: SOT-23 6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0005 ounces, 0.0141 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	-60		
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _A =25°C	l _D	-3.2		
	T _A =70°C		-2.5	Α	
Pulsed Drain Current		I _{DM} -12.8			
Power Dissipation	T _A =25°C	P _D	2	W	
	T _A =70°C		1.3		
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{ heta JA}$	62.5	°C/W	





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-60	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-1.0	-1.6	-2.5	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-3.2A	-	88	110	mΩ		
		V _{GS} =-4.5V,I _D =-1.6A	-	110	130			
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} =-60V, V_{GS} =0V	-	-	-1.0	uA		
Gate-Source Leakage Current	I _{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	<u>+</u> 100	nA		
Dynamic (Note 6)								
Total Gate Charge	Q_g	V _{DS} =-30V, I _D =-3.2A, V _{GS} =-10V (Note 1.2)	-	10	-	nC		
Gate-Source Charge	Q_gs		-	1.6	-			
Gate-Drain Charge	Q_gd		-	3	-			
Input Capacitance	Ciss	V _{DS} =-30V, V _{GS} =0V, f=1.0MHZ	-	785	-	pF		
Output Capacitance	Coss		-	176	-			
Reverse Transfer Capacitance	Crss		-	116	-			
Turn-On Delay Time	td _(on)	V_{DS} =-30V, I_{D} =-1A, V_{GS} =-10V, R_{G} =6.2 Ω (Note 1,2)	-	8	-			
Turn-On Rise Time	tr			15				
Turn-Off Delay Time	td _(off)		-	43	-			
Turn-Off Fall Time	tf		-	8.4	-			
Drain-Source Diode								
Maximum Continuous Drain-Source			-	-	-2	А		
Diode Forward Current	I _S							
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.77	-1	V		

NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- 4. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. R@JA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





TYPICAL CHARACTERISTIC CURVES

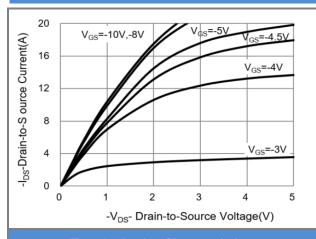


Fig.1 On-Region Characteristics

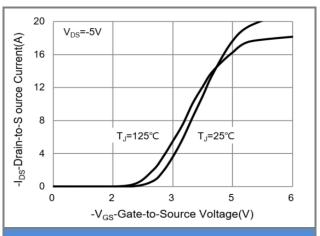


Fig.2 Transfer Characteristics

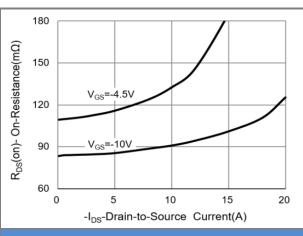


Fig.3 On-Resistance vs. Drain Current

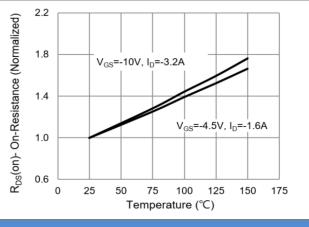


Fig.4 On-Resistance vs. Junction temperature

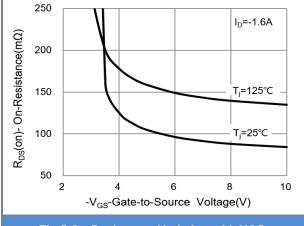


Fig.5 On-Resistance Variation with VGS.

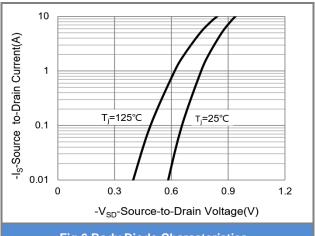


Fig.6 Body Diode Characteristics





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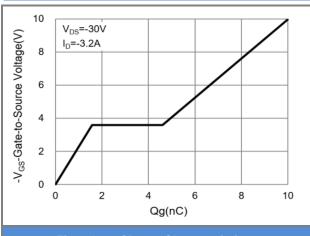


Fig.7 Gate-Charge Characteristics

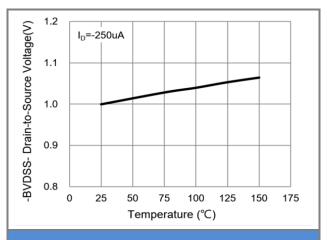


Fig.8 Breakdown Voltage Variation vs. Temperature.

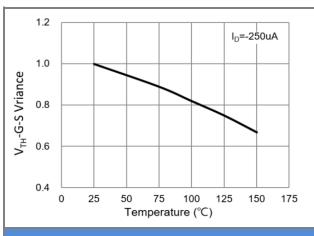


Fig.9 Threshold Voltage Variation with Temperature.

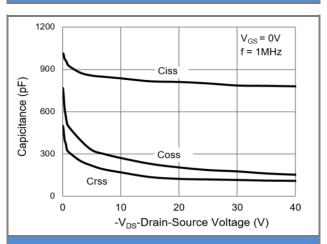


Fig.10 Capacitance vs. Drain-Source Voltage

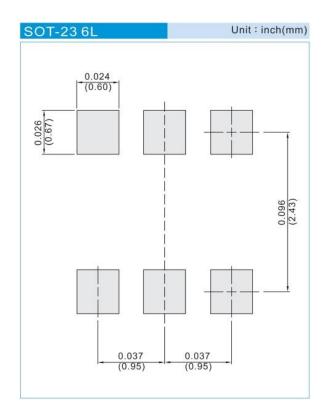




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJS6461_S1_00001	SOT-23 6L	3K pcs / 7" reel	S61	Halogen free

Mounting Pad Layout







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